

## Absolute Maximum Ratings

Voltages Referenced to Gnd

$V_{CC}$  ..... -0.5V to +7V

$V_{IN}$ ,  $V_{COM}$ ,  $V_{NC}$ ,  $V_{NO}$  <sup>(1)</sup> ..... -0.5V to  $V_{CC} + 2V$   
 ..... or 30mA, whichever occurs first

Current (any terminal except COM, NO, NC) ..... 30mA

Current, COM, NO, NC

(pulsed at 1ms, 10% duty cycle) ..... 120mA

### Notes:

1. Signals on NC, NO, COM, or IN exceeding  $V_{CC}$  or GND are clamped by internal diodes. Limit forward diode current to 30mA.
2. Caution: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.

## Thermal Information

Continuous Power Dissipation

Narrow SOIC & QSOP

(derate 8.7mW/°C above +70°C) ..... 650mW

Storage Temperature ..... -65°C to +150°C

Lead Temperature (soldering, 10s) ..... +300°C

## Electrical Specifications - Single +5V Supply ( $V_{CC} = +5V \pm 10\%$ , GND = 0V, $V_{INH} = 2.4V$ , $V_{INL} = 0.8V$ )

Parameter	Symbol	Test Conditions	Temp.	Min. <sup>(1)</sup>	Typ. <sup>(2)</sup>	Max. <sup>(1)</sup>	Units
<b>Analog Switch</b>							
Analog Switch Range <sup>(1)</sup>	$V_{ANALOG}$		Full	0		$V_{CC}$	V
On-Resistance	$R_{ON}$	$V_{CC} = 4.5V$ , $I_{COM} = -30mA$ , $V_{NO}$ or $V_{NC} = +2.5V$	25		8	10	$\Omega$
			Full			12	
On-Resistance Match Between Channels <sup>(6)</sup>	$\Delta R_{ON}$		25		0.8	2	
			Full			4	
On-Resistance Flatness <sup>(5)</sup>	$R_{FLAT(ON)}$	$V_{CC} = 5V$ , $I_{COM} = -30mA$ , $V_{NO}$ or $V_{NC} = +2.5V$	25		2	3	$\Omega$
			Full			4	
NO or NC OFF Leakage <sup>(6)</sup>	$I_{NO(OFF)}$ or $I_{NC(OFF)}$	$V_{CC} = 5.5V$ , $I_{COM} = 0V$ , $V_{NO}$ or $V_{NC} = 4.5V$	25		0.07		nA
			Full	-80		80	
COM OFF Leakage Current <sup>(6)</sup>	$I_{COM(OFF)}$	$V_{CC} = 5.5V$ , $I_{COM} = 4.5V$ , $V_{NO}$ or $V_{NC} = \pm 4.5V$	25		0.01		
			Full	-80		80	
COM ON Leakage Current <sup>(6)</sup>	$I_{COM(ON)}$	$V_{CC} = 5.5V$ , $I_{COM} = 4.5V$ , $V_{NO}$ or $V_{NC} = \pm 4.5V$	25		0.016		nA
			Full	-80		80	

**Electrical Specifications - Single +5V Supply** ( $V_{CC} = +5V \pm 10\%$ ,  $GND = 0V$ ,  $V_{INH} = 2.4V$ ,  $V_{INL} = 0.8V$ ) CONTINUED

Parameter	Symbol	TestConditions	Temp.	Min. <sup>(1)</sup>	Typ. <sup>(2)</sup>	Max. <sup>(1)</sup>	Units
Logic Input							
Input High Voltage	V <sub>IH</sub>	Guaranteed logic High Level	Full	2			V
Input Low Voltage	V <sub>IL</sub>	Guaranteed logic Low Level				0.8	
Input Current with Input Voltage High	I <sub>INH</sub>	V <sub>IN</sub> = 2.4V, all others = 0.8V	Full	-1	0.005	1	μA
Input Current with Input Voltage Low	I <sub>INL</sub>	V <sub>IN</sub> = 0.8V, all others = 2.4V		-1	0.005	1	
Dynamic							
Turn-On Time	t <sub>ON</sub>	V <sub>CC</sub> = 5V, See Figure 1	25		8	15	ns
			Full			20	
Turn-Off Time	t <sub>OFF</sub>		25		3.5	7	
			Full			10	
Charge Injection <sup>(3)</sup>	Q	C <sub>L</sub> = 1nF, V <sub>GEN</sub> = 0V, R <sub>GEN</sub> = 0Ω, See Figure 2	25			10	pC
Off Isolations	O <sub>IRR</sub>	R <sub>L</sub> = 50Ω, C <sub>L</sub> = 5pF, f = 10MHz, See Figure 3			-57		dB
Crosstalk <sup>(8)</sup>	X <sub>TALK</sub>	R <sub>L</sub> = 50Ω, C <sub>L</sub> = 5pF, f = 10MHz, See Figure 4			-100		
NC or NO Capacitance	C <sub>(OFF)</sub>	f=1kHz, See Figure 5			8		pF
COM OFF Capacitance	C <sub>COM(OFF)</sub>				14		
COM ON Capacitance	C <sub>COM(ON)</sub>	f = 1kHz, See Figure 6			18		
-3db Bandwidth	BW	R <sub>L</sub> = 50Ω See Figure 7	Full		230		MHz
Distortion	D	R <sub>L</sub> = 10kΩ			0.2		%
Supply							
Power-Supply	V <sub>CC</sub>		Full	2		6	V
Postitive Supply Current	I <sub>CC</sub>	V <sub>CC</sub> = 5.5V, V <sub>IN</sub> = 0V or V <sub>CC</sub> , all channels on or off				1	μA

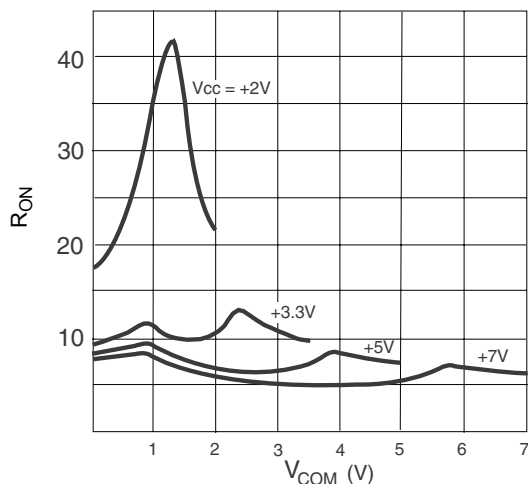
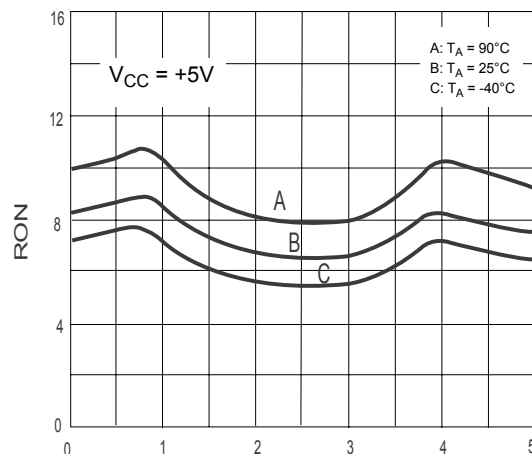
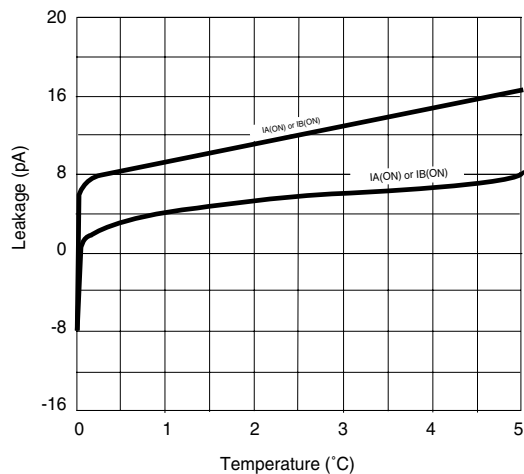
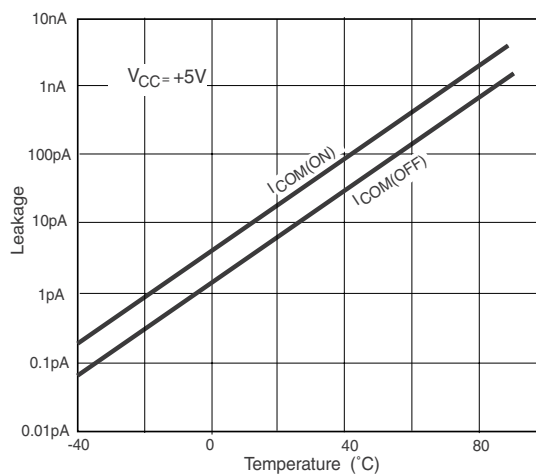
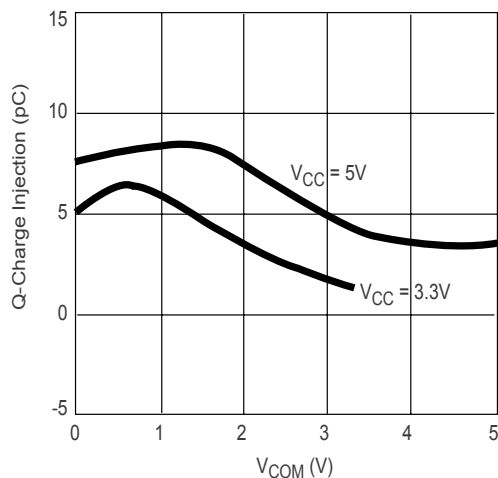
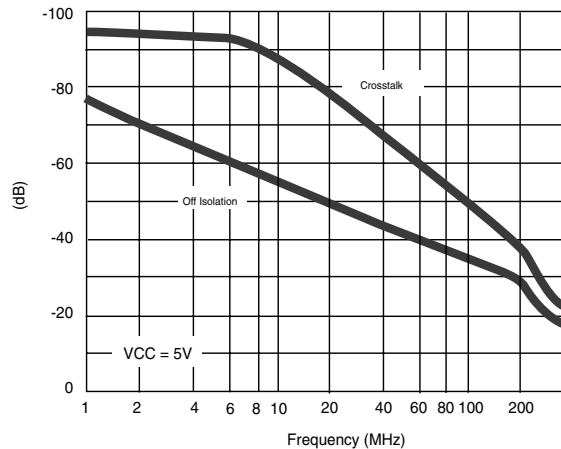
**Notes:**

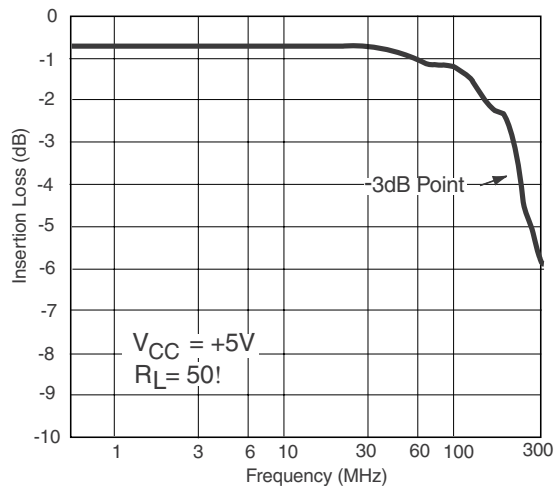
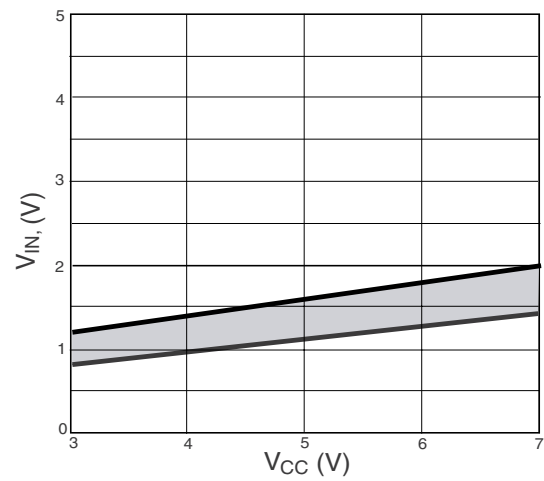
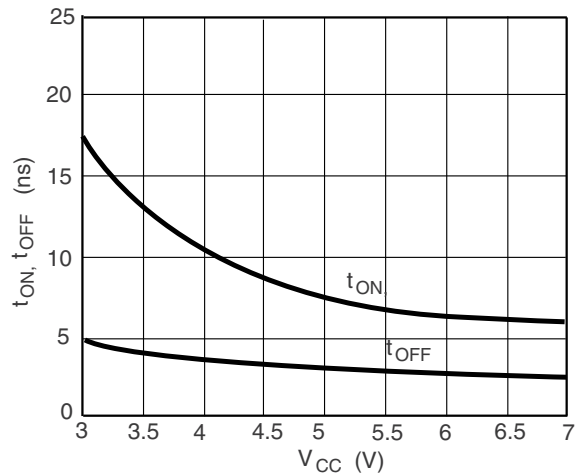
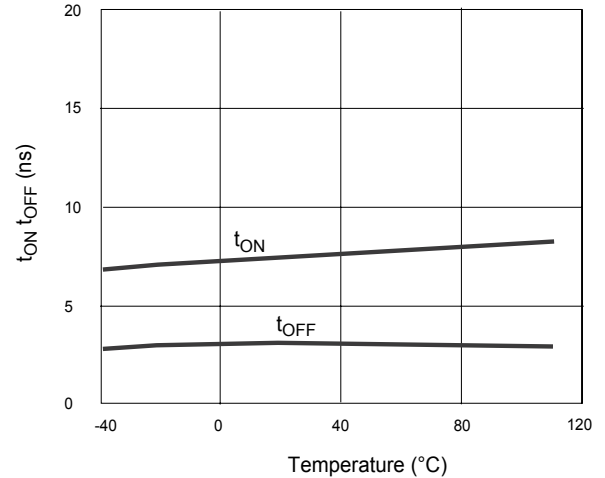
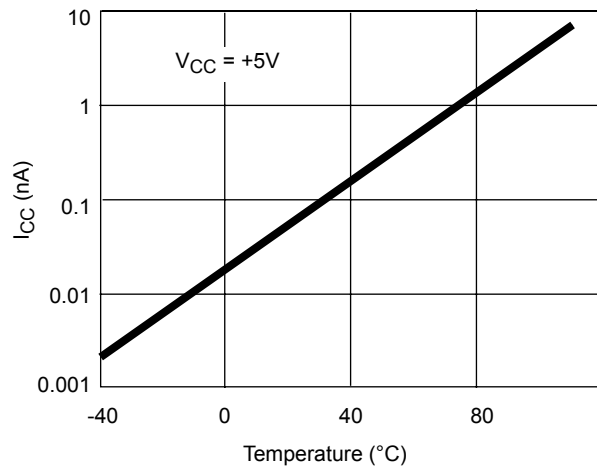
- The algebraic convention, where the most negative value is a minimum and the most positive is a maximum, is used in this data sheet.
- Typical values are for DESIGN AID ONLY, not guaranteed or subject to production testing.
- Guaranteed by design
- $\Delta R_{ON} = R_{ON \max} - R_{ON \min}$
- Flatness is defined as the difference between the maximum and minimum value of On-Resistance measured.
- Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at +25°C.
- Off Isolation =  $20 \log_{10} [ V_{COM} / (V_{NO} \text{ or } V_{NC}) ]$ . See figure 3.
- Between any two switches. See figure 4.-

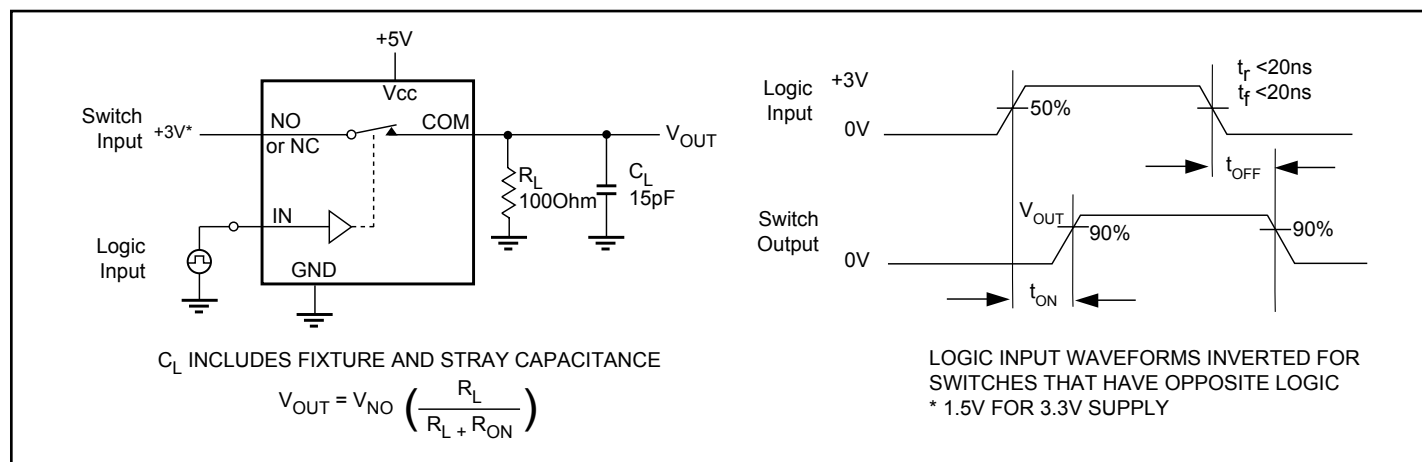
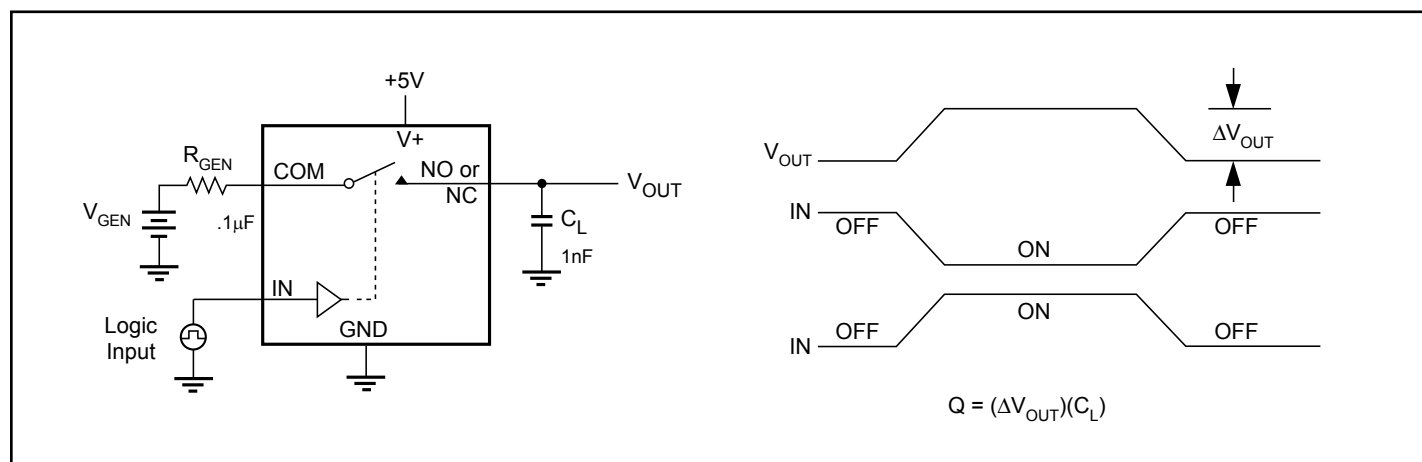
**Electrical Specifications - Single +3.3V Supply** ( $V_{CC} = +5V \pm 10\%$ ,  $GND = 0V$ ,  $V_{INH} = 2.4V$ ,  $V_{INL} = 0.8V$ )

Parameter	Symbol	TestConditions	Temp.	Min. <sup>(1)</sup>	Typ. <sup>(2)</sup>	Max. <sup>(1)</sup>	Units
Analog Switch							
Analog Switch Range <sup>(1)</sup>				0		V <sub>CC</sub>	V
On-Resistance	R <sub>ON</sub>	V <sub>CC</sub> = 4.5V, I <sub>COM</sub> = -30mA, V <sub>NO</sub> or V <sub>NC</sub> = +2.5V	25		12	18	Ω
On-Resistance Match Between Channels <sup>(6)</sup>	ΔR <sub>ON</sub>		Full				
			25		5		
On-Resistance Flatness <sup>(5)</sup>	R <sub>FLAT(ON)</sub>		Full				
		25		2	4		
		Full			5		
Dynamic							
Turn-On Time	t <sub>ON</sub>	V <sub>CC</sub> = 5V, See Figure 1	25		14	25	ns
Turn-Off Time	t <sub>OFF</sub>		Full			40	
			25		4.5	12	
			Full			20	
Charge Injection <sup>(3)</sup>	Q	C <sub>L</sub> = 1nF, V <sub>GEN</sub> = 0V, R <sub>GEN</sub> = 0Ω, See Figure 2	25		5	10	pC
Supply							
Postitive Supply Current	I <sub>CC</sub>	V <sub>CC</sub> = 3.6V, V <sub>IN</sub> = 0V or V <sub>CC</sub> , all channels on or off	Full			1	μA

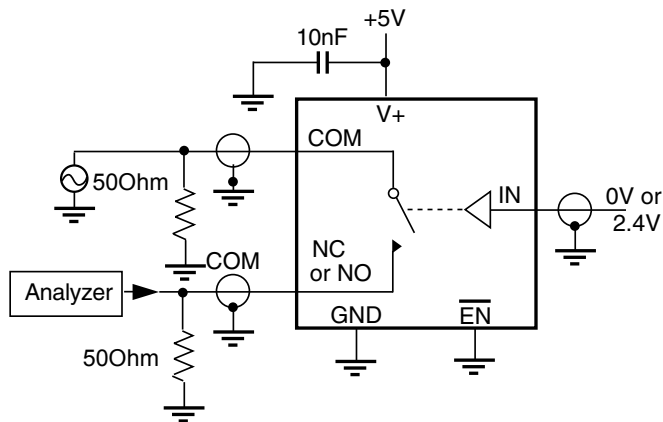
**Typical Operating Characteristics** ( $T_A = +25^\circ\text{C}$ , unless otherwise noted)

 **$R_{ON}$  vs.  $V_{COM}$** 

 **$R_{ON}$  vs.  $V_{COM}$  and Temperature**

**Leakage Currents vs. Analog Voltage**

**Leakage Current vs. Temperature**

**Charge Injection vs. Analog Voltage**

**Crosstalk and Off-Isolation vs. Frequency**


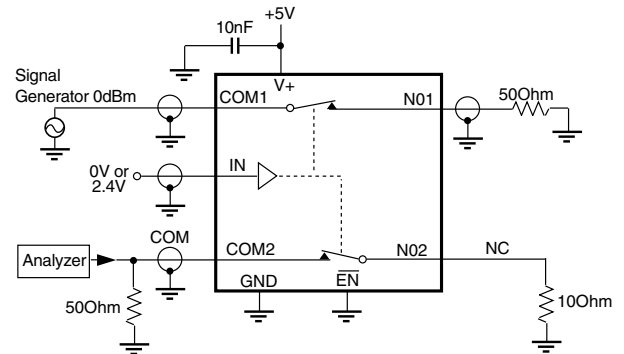
**Insertion Loss vs. Frequency**

**Input Switching Threshold vs. Supply Voltage**

 **$R_{ON}$  vs.  $V_{COM}$  and Single Supply**

**Switching Times vs. Temperature**

**Supply Current vs. Temperature**


**Test Circuits/Timing Diagrams**

**Figure 1. Switching Time**

**Figure 2. Charge Injection**

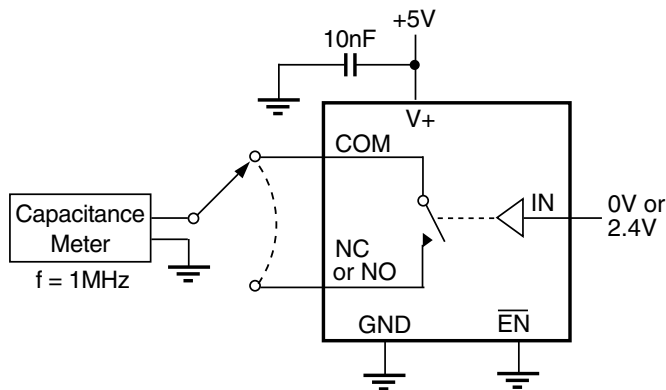
**Test Circuits/Timing Diagrams (continued)**



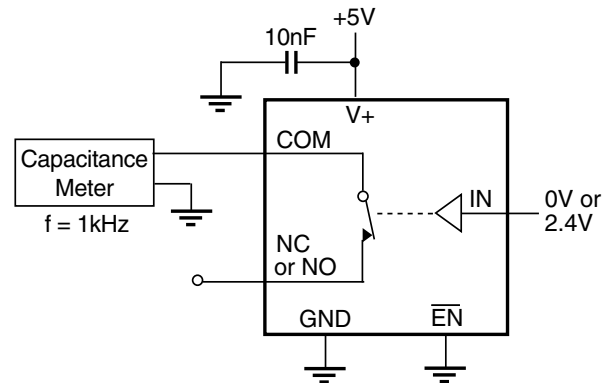
**Figure 3. Off Isolation**



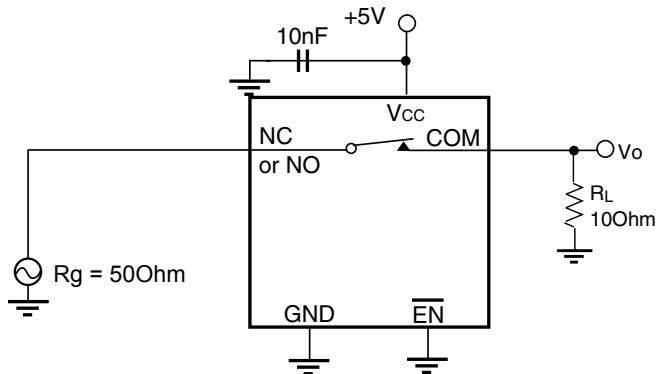
**Figure 4. Crosstalk**



**Figure 5. Channel-Off Capacitance**



**Figure 6. Channel-On Capacitance**



**Figure 7. Bandwidth**

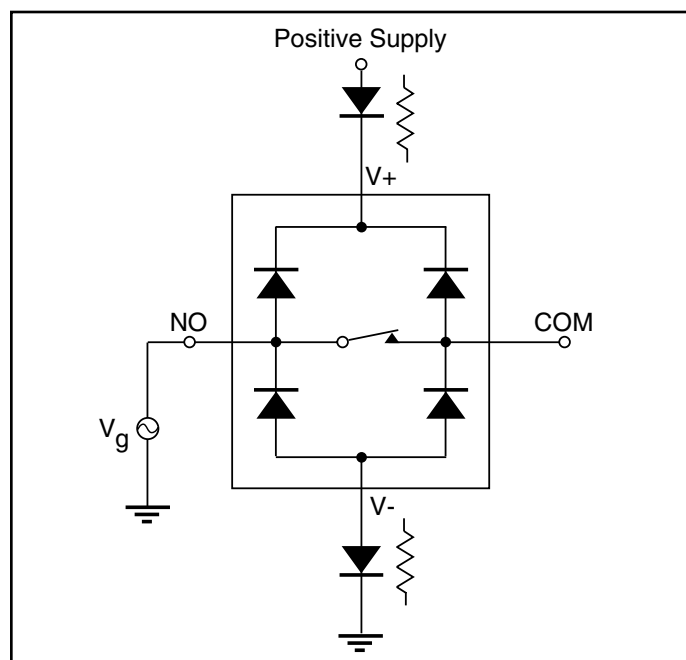
## Applications Information

### Overvoltage Protection

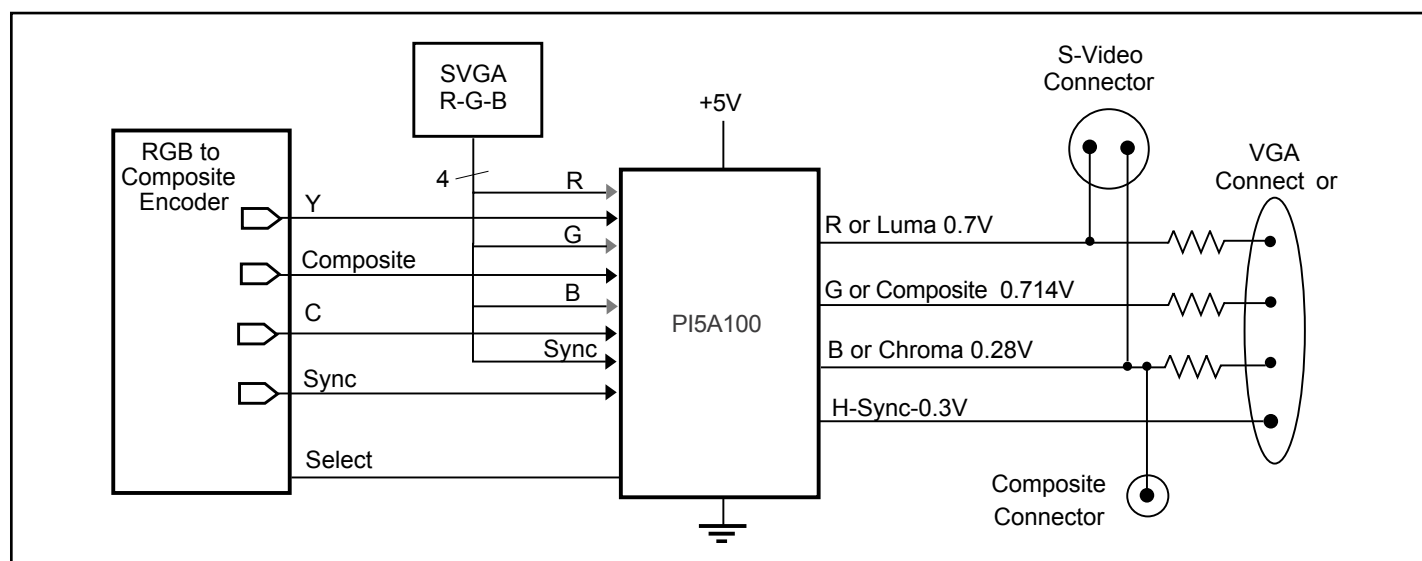
Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, followed by V-, and then logic inputs. If power-supply sequencing is not possible, add two small signal diodes or two current limiting resistors in series with the supply pins for overvoltage protection (Figure 8). Adding diodes reduces the analog signal range, but low switch resistance and low leakage characteristics are unaffected.

### RGB Switch

Figure 9 illustrates a simple low cost RGB switch. The RGB - to-Composite Decoder produces either NTSC or S-VHS video from an RGB source. A single PI5A100 selects one of the two video sources to produce either SVHS, Composite or RGB video outputs. The low insertion loss of the PI5A100 eliminates the need for expensive input/output buffers.



**Figure 8:** Overvoltage protection is accomplished using two external blocking diodes or two current limiting resistors.



**Figure 9:** The single PI5A100 is used to select SVHS, VGA or Composite video outputs.



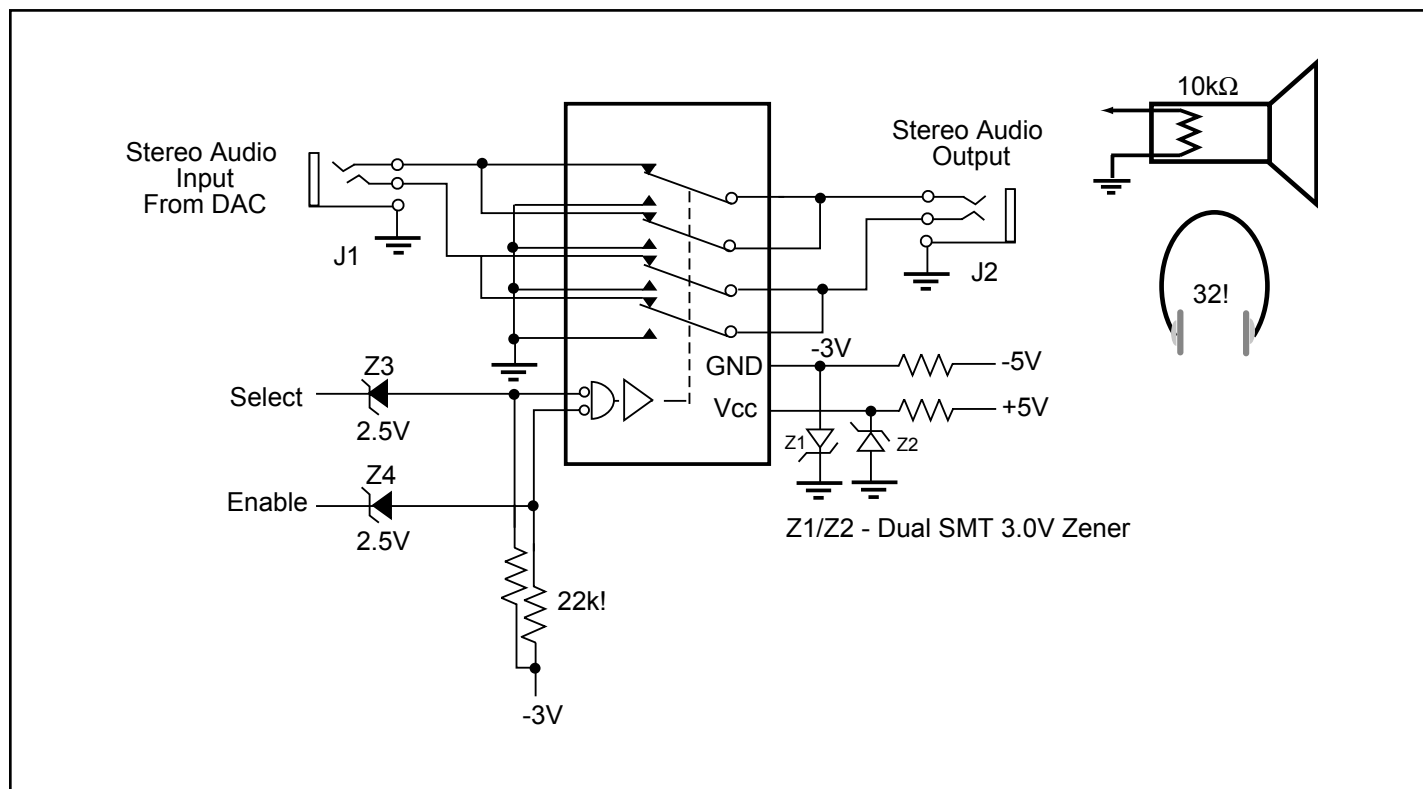
## Applications

### Audio Muting Function

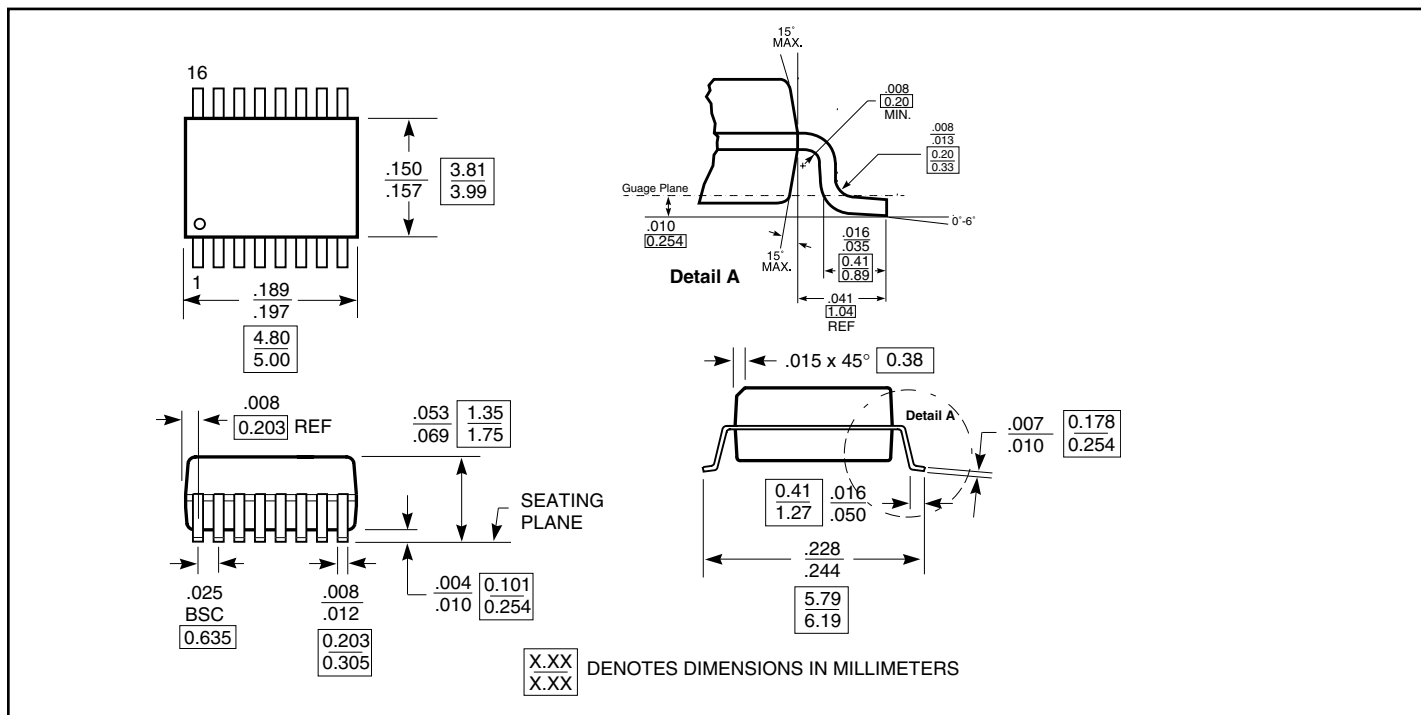
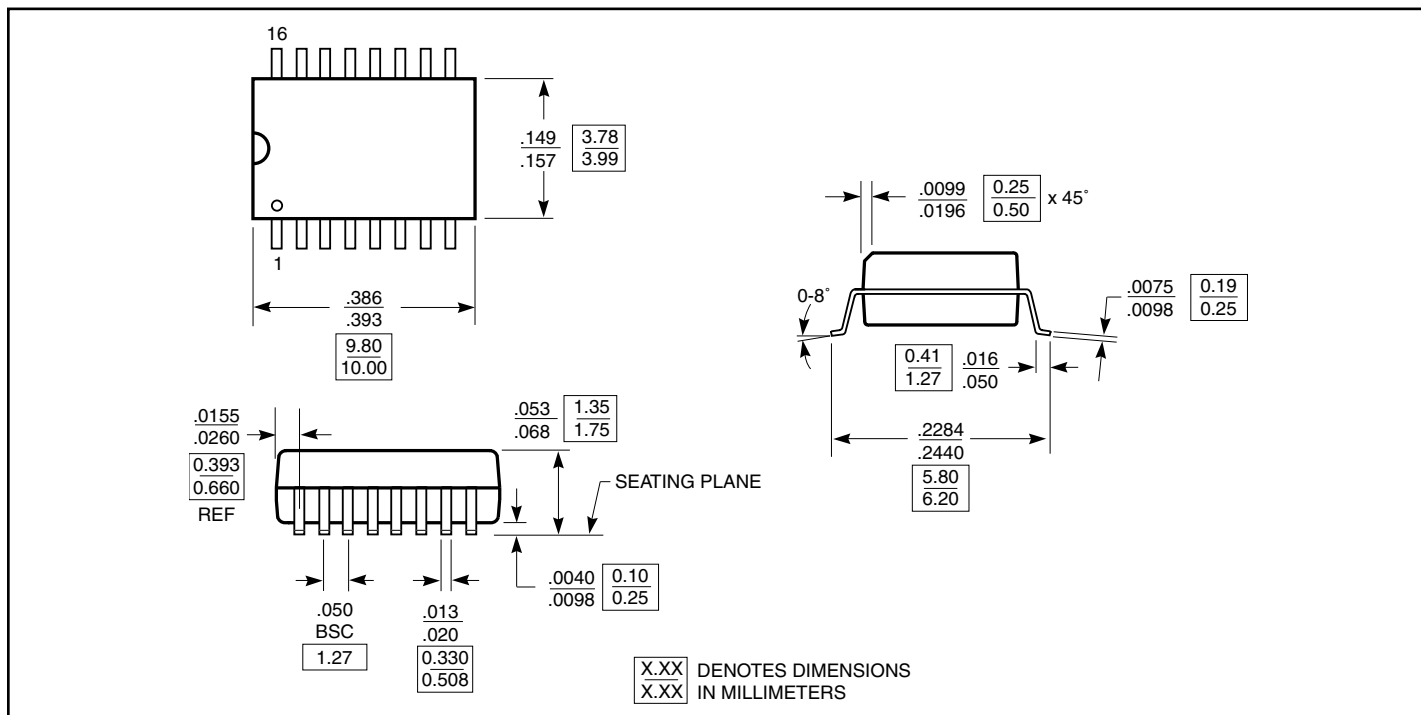
Figure 8 shows the PI5A100 in an audio card muting application. The original problem was one of excessive popping/clicking noise appearing when connecting/disconnecting external loads, and at power on/off. The PI5A100 performs a muting function by grounding the outputs at power on/off and during the transition time. The 32Ω headset impedance demands a very low and very flat switch-on resistance to reduce THD and signal loss.

Paralleling two sections of the PI5A100 produces a  $R_{on}$  of  $2.5\Omega$  with an unsurpassed  $\pm 0.5\Omega$  flatness.

To handle AC signals it was necessary to power the device with  $\pm 3V$  provided by two Zener diodes: Z1 and Z2. The select and Enable control signals are shifted by using two 2.5V Zener diodes Z3, Z4 and pull down resistors connected to -3V.



**Figure 10:** The PI5A100 momentarily mutes the stereo outputs by connecting them to ground during transition times.

**Packaging Mechanical: 16-Pin QSOP (Q)**

**Packaging Mechanical: 16-Pin SOIC (W)**


**Ordering Information**

Ordering Code	Package Code	Package Description
PI5A100W	W	16-pin SOIC
PI5A100Q	Q	16-pin QSOP
PI5A100QE	Q	Pb-free & Green, 16-pin QSOP

**Notes:**

1. Thermal characteristics can be found on the company web site at [www.pericom.com/packaging/](http://www.pericom.com/packaging/)
- 2., Number of Transistors = TBD